

NSN 5962-01-290-2307 Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-290-2307 **Overall Length:** 1.290 inches **Overall Height:** 0.425 inches **Body Length:** 1.290 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** Between 0.150 inches and 0.210 inches **Maximum Power Dissipation Rating:** 1.1 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** Electrostatic sensitive and programmed and hermetically sealed and burn in and schottky

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

14 input

Case Outline Source And Designator:

D-3 mil-m-38510

Current Rating Per Characteristic:

185.00 milliamperes supply

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

90.00 nanoseconds access

Memory Device Type:

Prom

Memory Capacity:

Unknown

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type A	and Quantity	/ :
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24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0